Key Features



- 8.0 ~ 18.0 GHz
- 2.0 dB noise figure
- 19.0 dBm output P_{1dB}
- 35.0 dB Gain
- +/-1.5 dB Gain Flatness
- 1.8:1 VSWR
- Single power supply
- >34 years MTBF
- Unconditional stable
- RoHS compliant

Product Description

WBA80180B integrates WanTcom proprietary low noise amplifier technology, high frequency micro electronic assembly techniques, and high reliability design to realize optimum low noise figure, wideband, high linearity, and unconditional stable performances together. With single +5.0V DC operation, the amplifier has optimal input and output matching in the specified frequency range at 50-Ohm impedance system. The amplifier has standard field replaceable SMA connectorized WP-10D gold plated housing.

The amplifier is designed to meet the rugged standard of MIL-STD-202.

Applications

- Microwave Radio
- Satellite VSAT & DBS
- 802.16 & 802.20 WiMAX
- WLL & MMDS
- Test Instrument

Specifications

Summary of the electrical specifications WBA80180B at room temperature

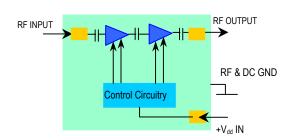
| Index | Testing Item | Symbol | Test Constraints | Min | Nom | Max | Unit |
|-------|------------------------------------|---------------------|------------------------|------|---------|-------|-------|
| 1 | Gain | S ₂₁ | 8.0 – 18.0 GHz | | 35 | | dB |
| 2 | Gain Variation | ΔG | 8.0 – 18.0 GHz | | +/- 1.5 | | dB |
| 3 | Input VSWR | SWR ₁ | 8.0 – 18.0 GHz | | 1.8:1 | 2.4:1 | Ratio |
| 4 | Output VSWR | SWR ₂ | 8.0 – 18.0 GHz | | 1.8:1 | 2.0:1 | Ratio |
| 5 | Reverse Isolation | S ₁₂ | 8.0 – 18.0 GHz | 40 | | | dB |
| 6 | Noise figure | NF | 8.0 – 18.0 GHz | | 2.0 | 2.5 | dB |
| 7 | Output Power 1dB compression Point | P _{1dB} | 8.0 – 18.0 GHz | | 19 | | dBm |
| 8 | Current Consumption | I _{dd} | V _{dd} = +5 V | | 150 | | mA |
| 9 | Power Supply Voltage | V_{dd} | | +4.7 | +5 | +5.3 | V |
| 10 | Operating Temperature | To | | -40 | | +85 | °C |
| 11 | Maximum Average RF Input Power | P _{IN MAX} | 8.0 – 18.0 GHz | | | 15 | dBm |

Absolute Maximum Ratings

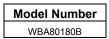
| Parameters | Units | Ratings |
|-------------------------|-------|-----------|
| DC Power Supply Voltage | V | 6.0 |
| Drain Current | mA | 200 |
| Total Power Dissipation | mW | 1000 |
| RF Input Power | dBm | 15 |
| Channel Temperature | °C | 175 |
| Storage Temperature | °C | -55 ~ 125 |
| Operating Temperature | °C | -40 ~ 85 |

Operation of this device above any one of these parameters may cause permanent damage.

Functional Block Diagram

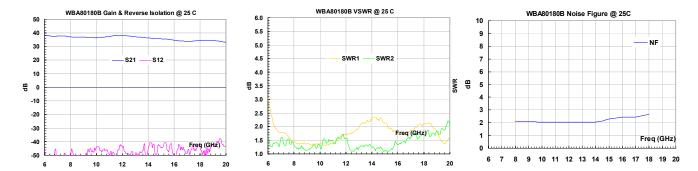


Ordering Information



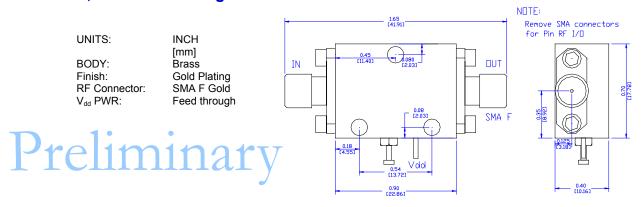


Typical Data



*The measured noise figure includes the input SMA connector loss. The noise figure shall be around $0.1 \sim 0.2$ dB lower without SMA connector.

Outline, WP-10D Housing



For the pin type input and output application, remove the input and output SMA connectors.

Application Notes:

A. SMA Torque Wrench Selection

Always use a torque wrench with $5 \sim 6$ inch-lb coupling torque setting for mating the SMA cables to the amplifier. Never use torque more than 8 inch-lb wrench for tightening the mating cable to the connector. Otherwise, the permanent damage will occur to the SMA connectors of the amplifier. 8710-1582 (5 inch-lb) is one of the ideal torque wrench choice from Agilent Technology.

B. Mounting the Amplifier

Use three pieces of #4-40 with longer than 9/16" screws for mounting the amplifier on a metal-based chase. Flat and spring washers are needed to prevent the screw loosening during the shock and vibration. Always use the appropriate torque setting of the power screwdriver to mount them.
